## NSN 5961-01-016-8487

Thyristor Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-016-8487 **Inclosure Material:** Ceramic **Overall Length:** 0.550 inches **Overall Diameter:** 1.500 inches **Mounting Method:** Compression **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 600.0 off-state voltage, rms total **Current Rating Per Characteristic:** 400.00 amperes drain current nanoamperes **Power Rating Per Characteristic:** 2.0 watts small-signal input power, common-collector peak **Maximum Operating Tempurature Per Measurement Point:** 125.0 degrees celsius junction **Terminal Type And Quantity:** 2 tab, solder lug Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig:

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